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Kwon

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(54) **METHOD OF MANUFACTURING ORGANIC
LIGHT-EMITTING DISPLAY APPARATUS**

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(30) **Foreign Application Priority Data**

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(51) **Int. Cl.**

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H01L 51/50 (2006.01)
H01L 51/52 (2006.01)
H01L 27/32 (2006.01)
H01L 51/56 (2006.01)

(52) **U.S. Cl.**

CPC **H01L 51/0016** (2013.01); **H01L 27/3246**
(2013.01); **H01L 51/50** (2013.01); **H01L**
2227/323 (2013.01)

(58) **Field of Classification Search**

CPC **H01L 51/50**
See application file for complete search history.

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Primary Examiner — Caleb Henry

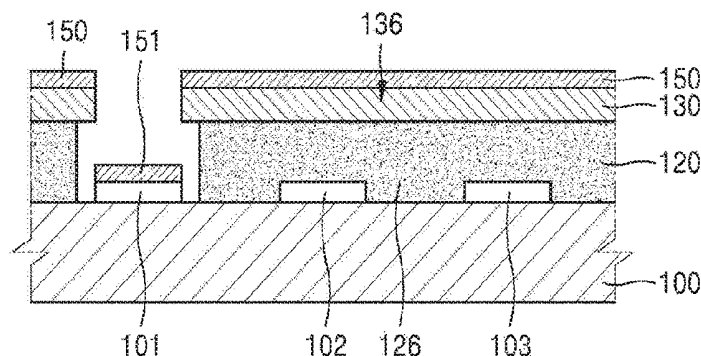
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PLC

(57) **ABSTRACT**

A method of manufacturing an organic light-emitting display apparatus includes forming an anode on a substrate, forming a lift-off layer on the substrate including the anode, the lift-off layer including a fluoropolymer, forming a polymer layer on the lift-off layer, forming a pattern on a first portion of the polymer layer overlapping the anode using a roll-to-roll stamp process, etching a first portion of the lift-off layer corresponding to the pattern using a first solvent including fluorine, the first portion of the lift-off layer being disposed on the anode, forming an organic functional layer including a light-emitting layer on the anode and a second portion of the polymer layer not formed with the pattern, removing the lift-off layer using a second solvent including fluorine, and forming a cathode on the organic functional layer.

16 Claims, 36 Drawing Sheets



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FIG. 1

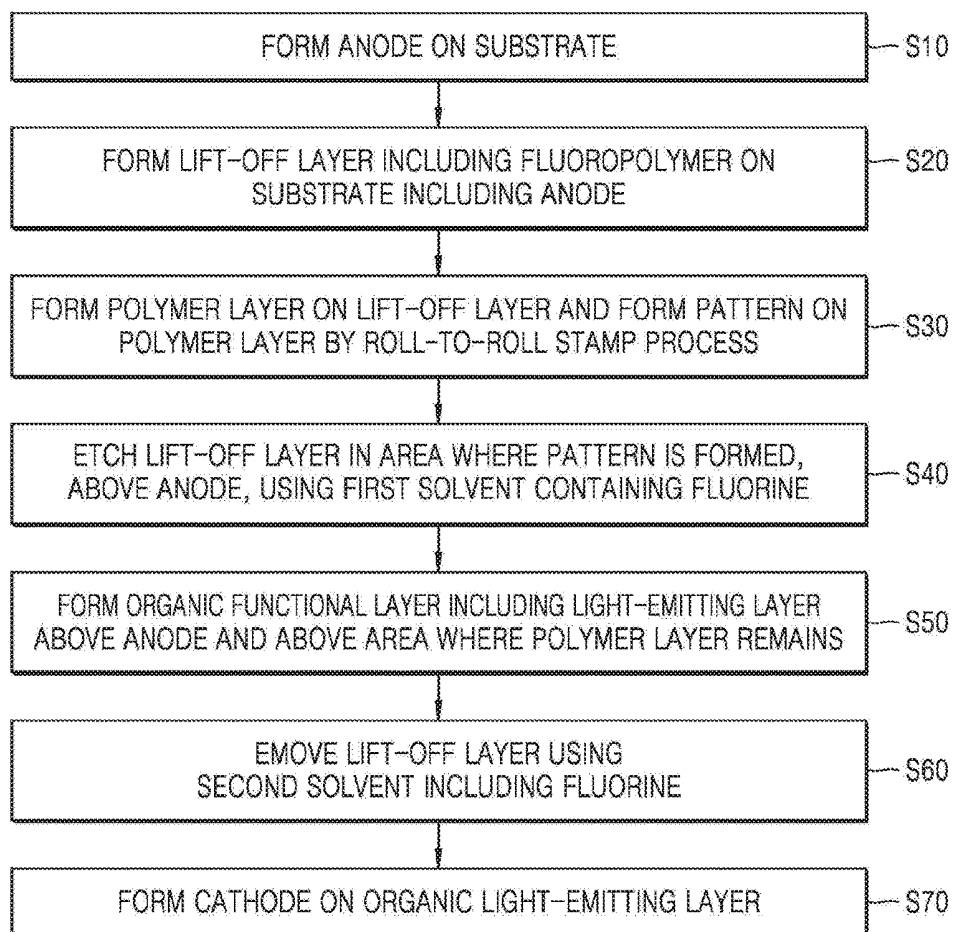


FIG. 2

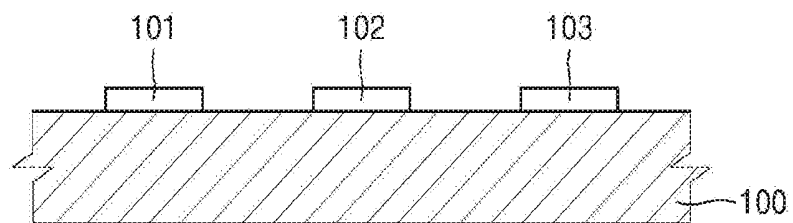


FIG. 3A

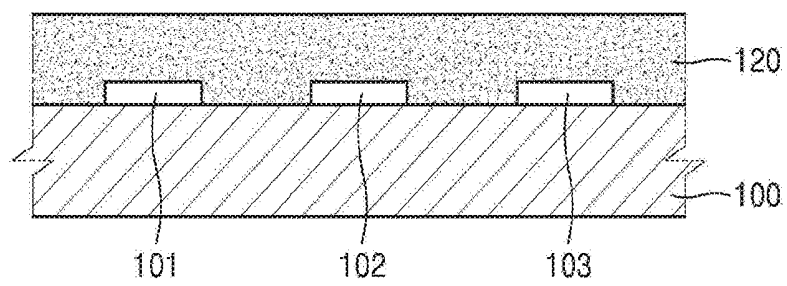


FIG. 3B

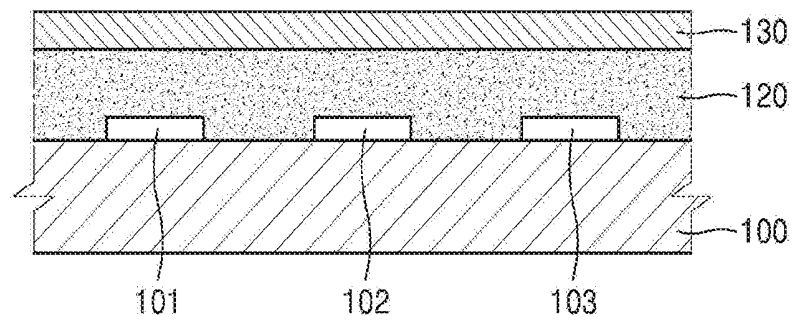


FIG. 3C

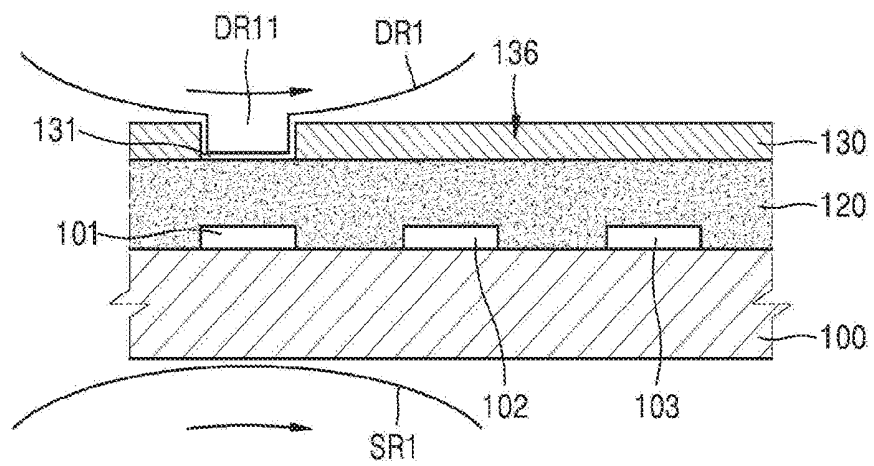


FIG. 3D

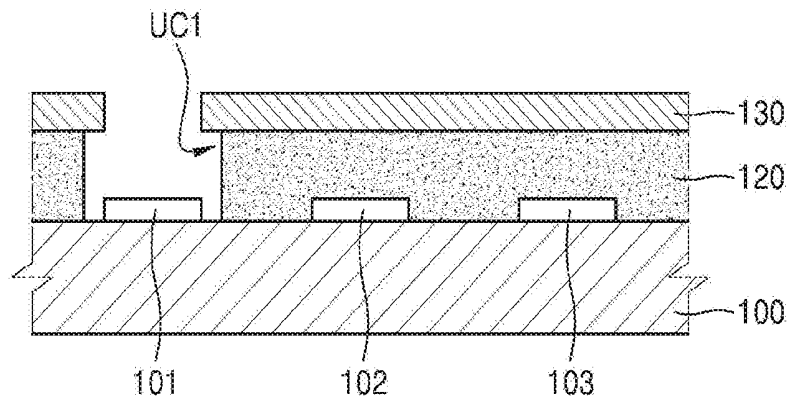


FIG. 3E

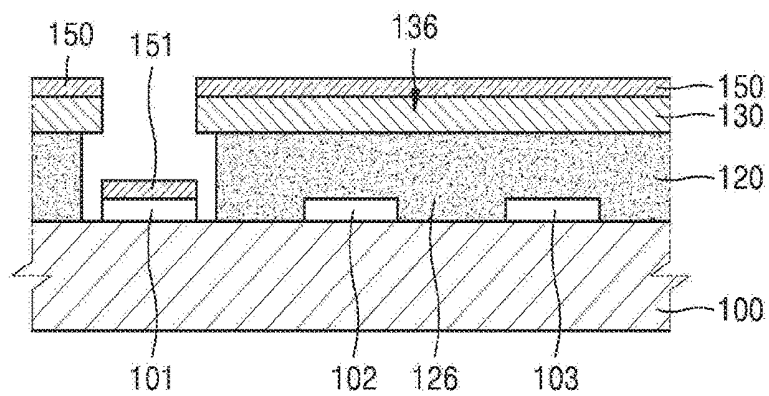


FIG. 3F

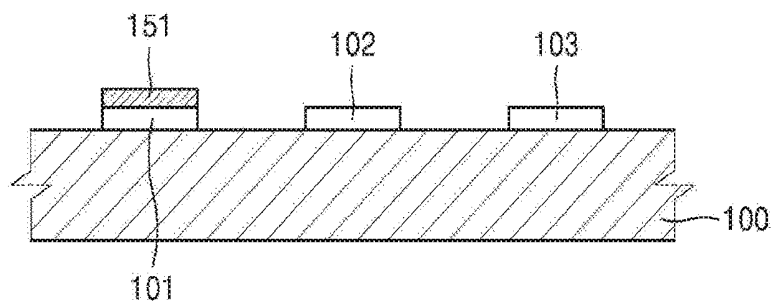


FIG. 4A

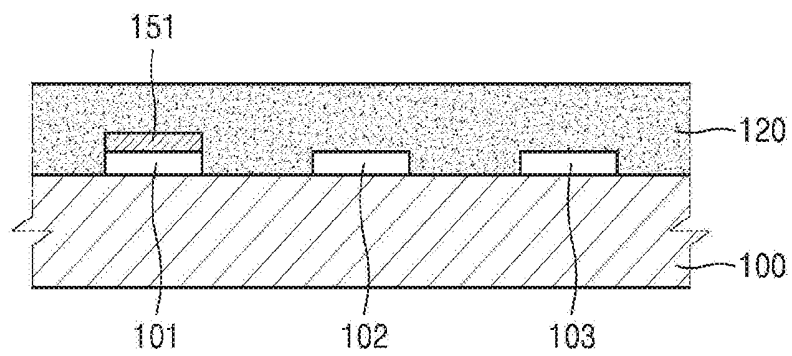


FIG. 4B

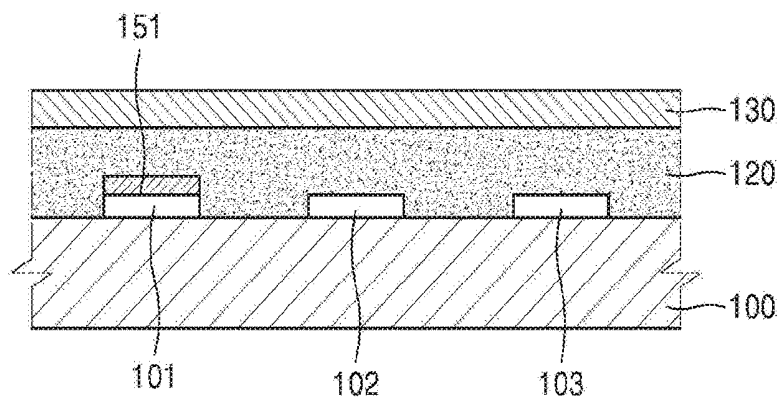


FIG. 4C

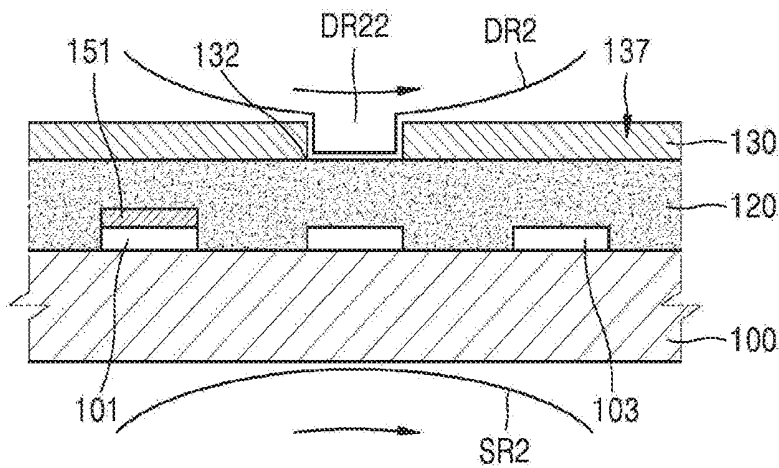


FIG. 4D

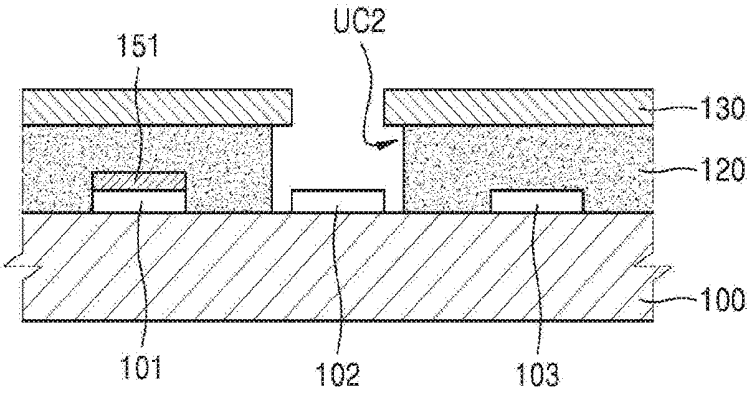


FIG. 4E

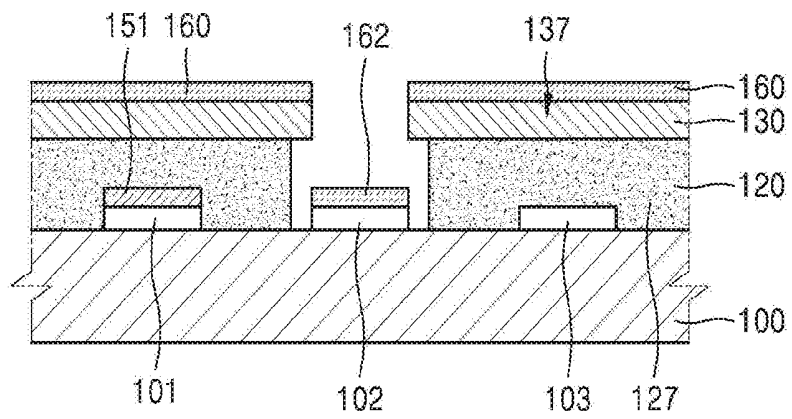


FIG. 4F

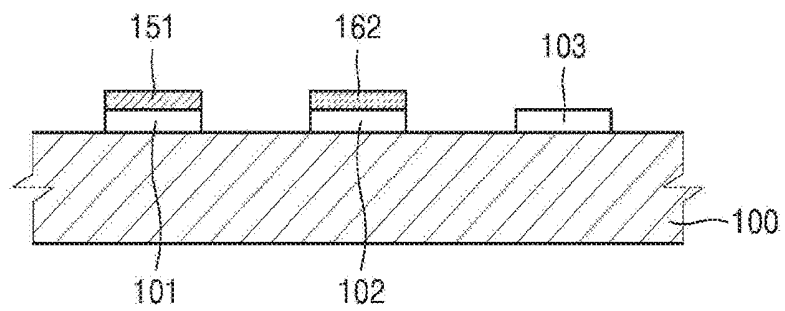


FIG. 5A

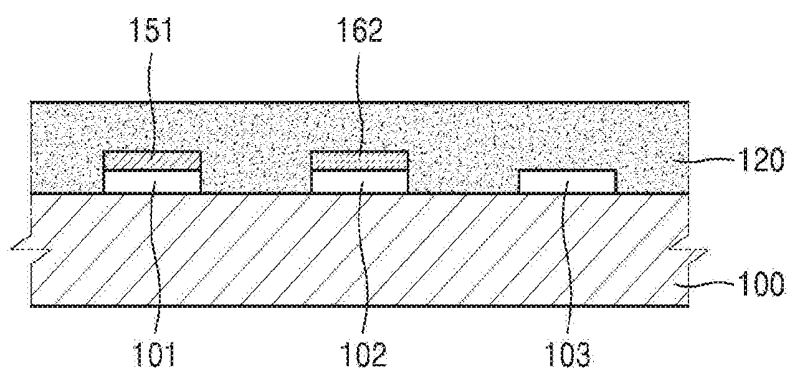


FIG. 5B

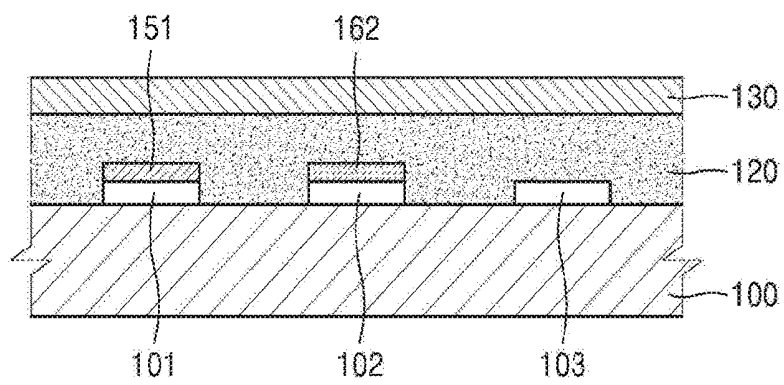


FIG. 5C

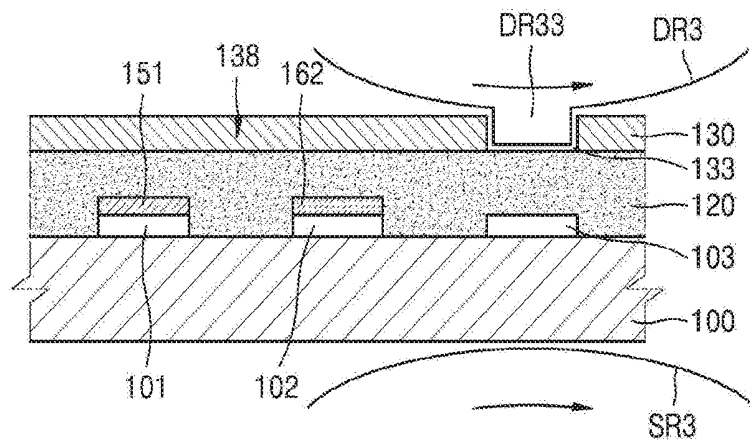


FIG. 5D

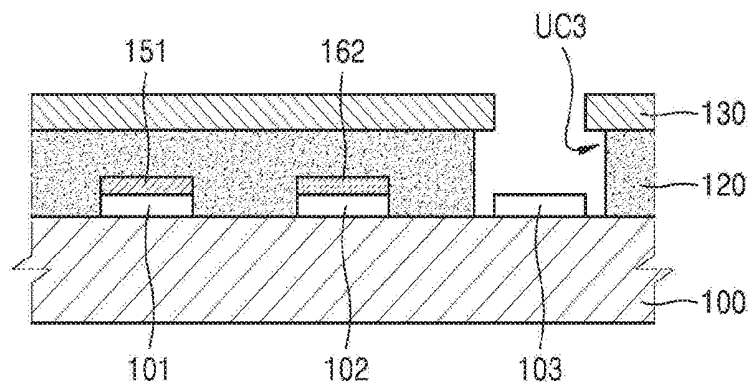


FIG. 5E

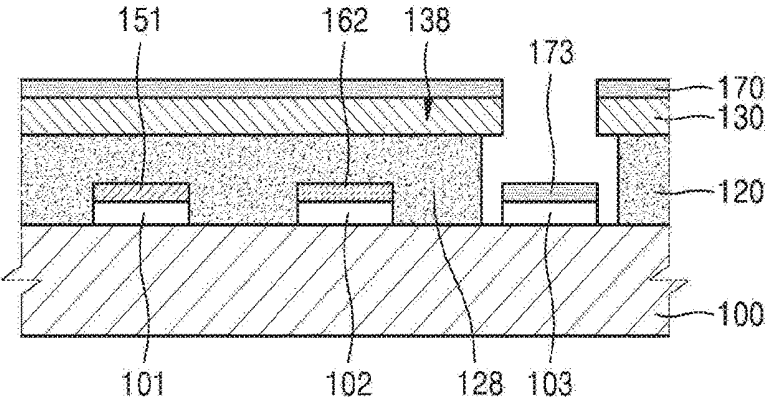


FIG. 5F

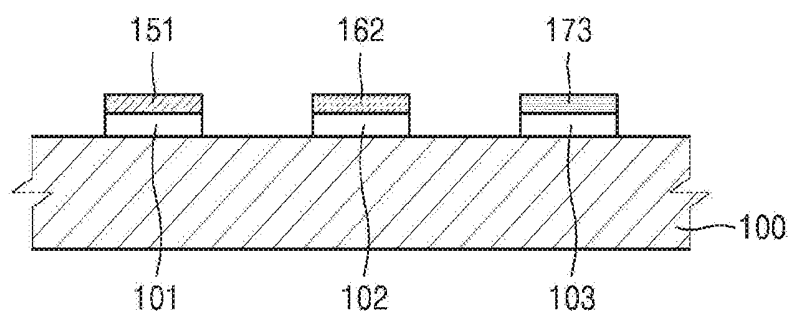


FIG. 6

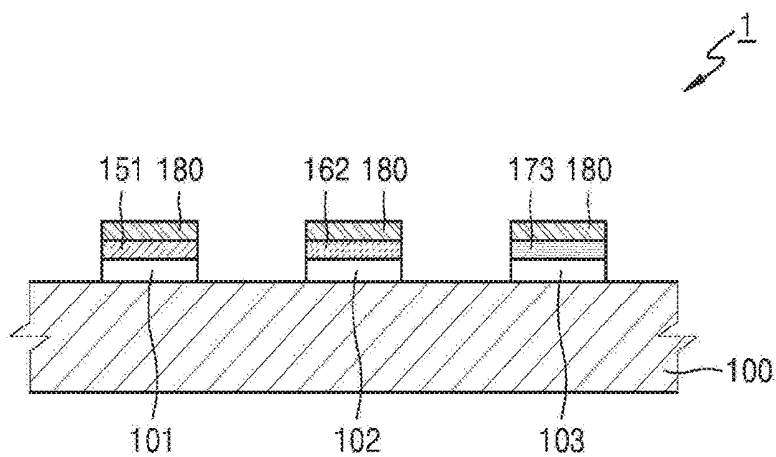
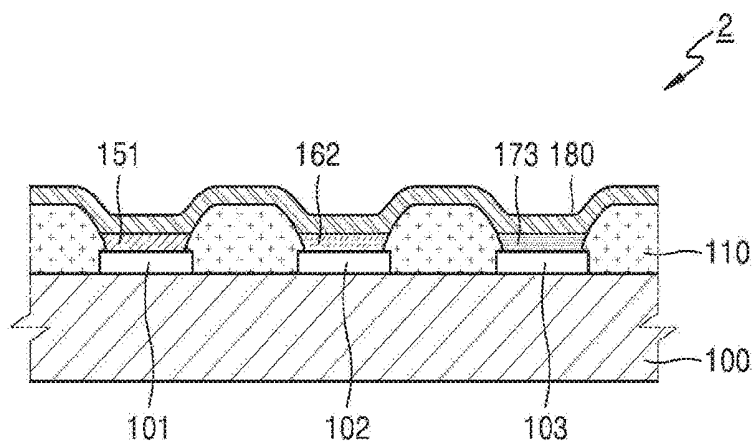


FIG. 7



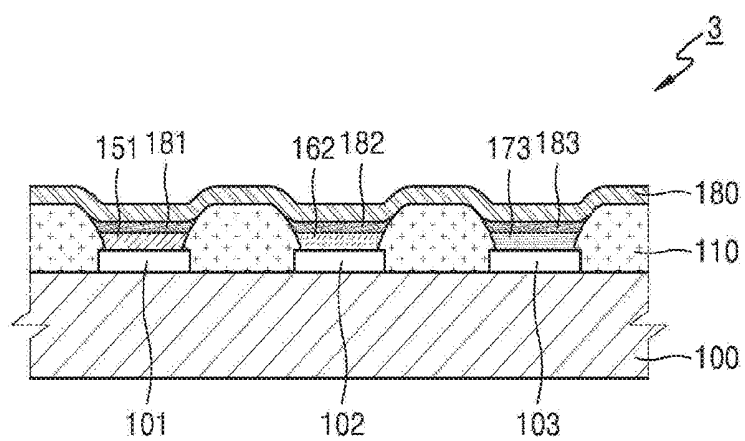


FIG. 9

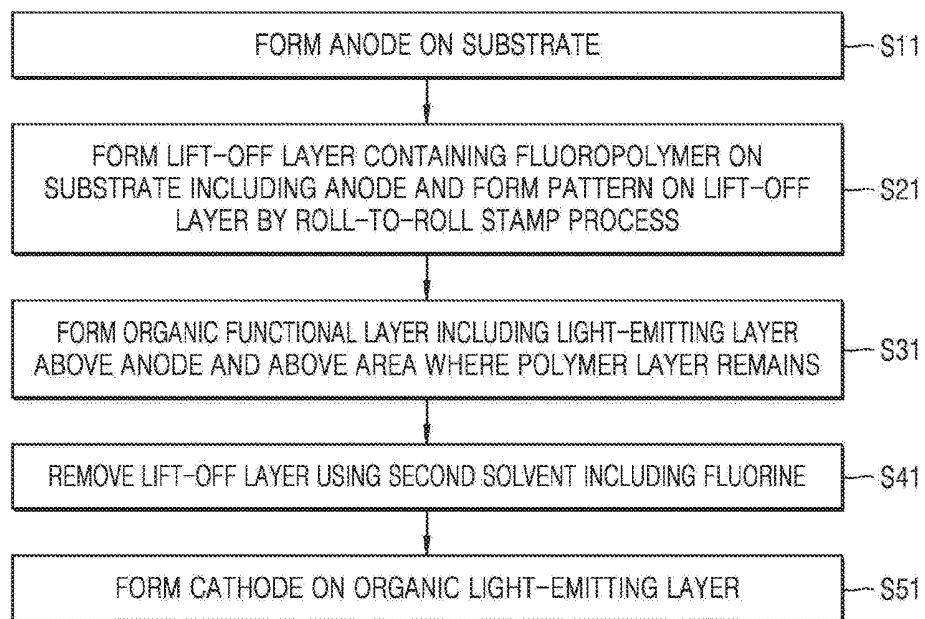


FIG. 10A

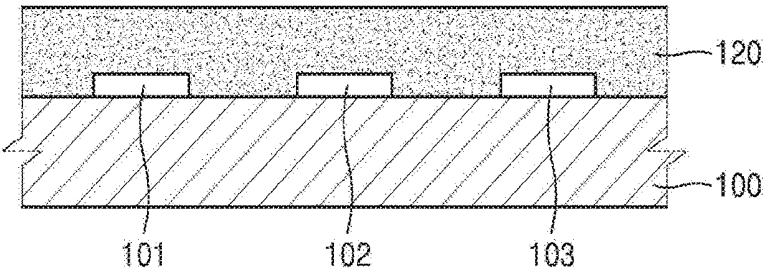


FIG. 10B

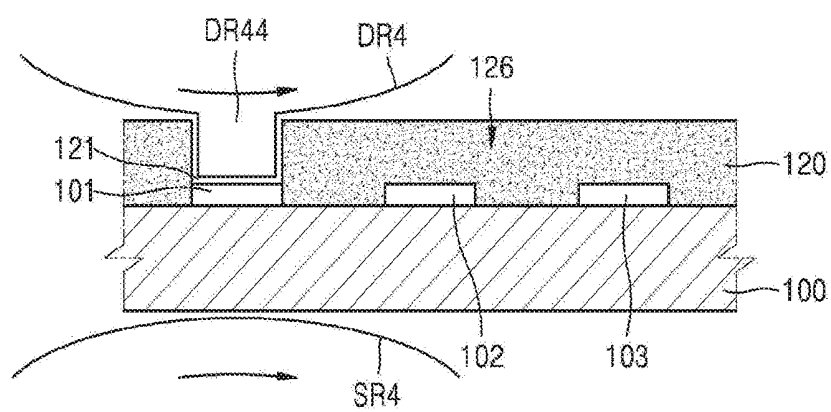


FIG. 10C

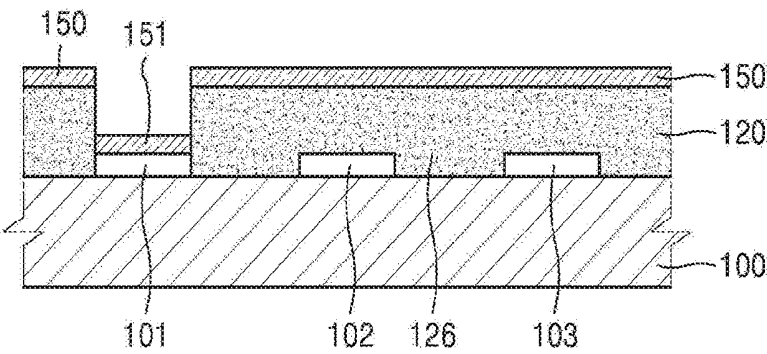


FIG. 10D

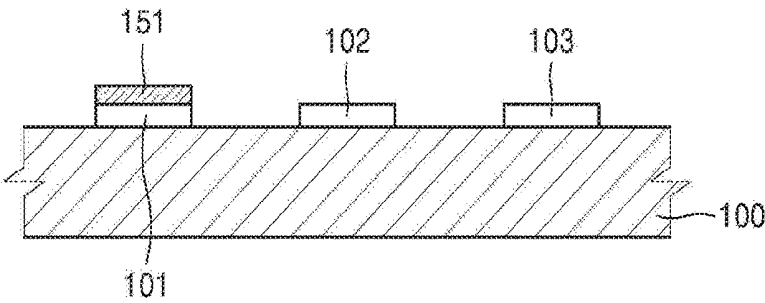


FIG. 11A

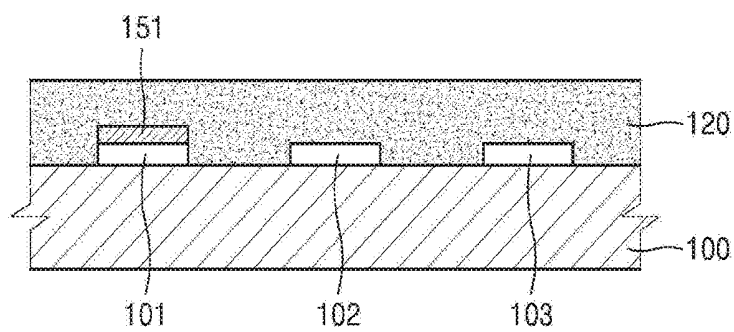


FIG. 11B

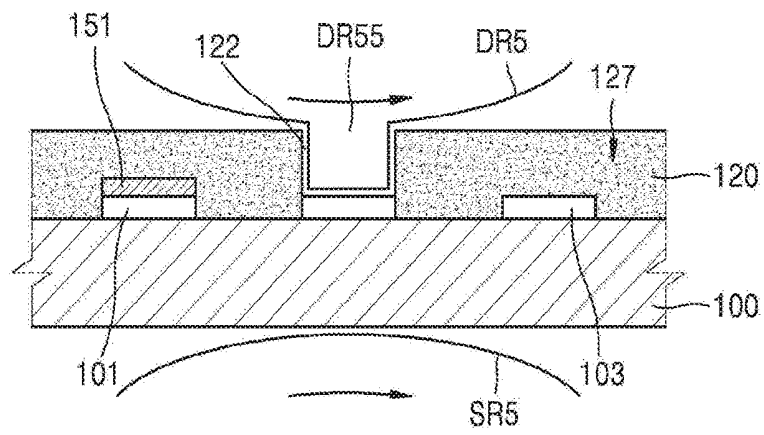


FIG. 11C

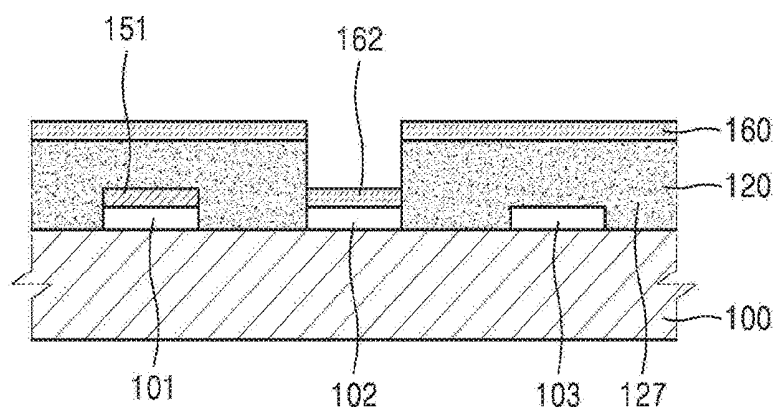


FIG. 11D

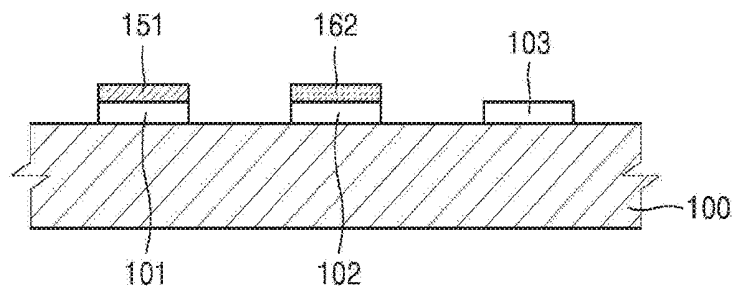


FIG. 12A

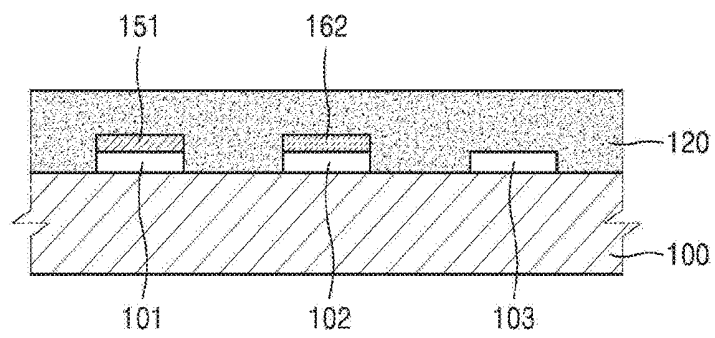


FIG. 12B

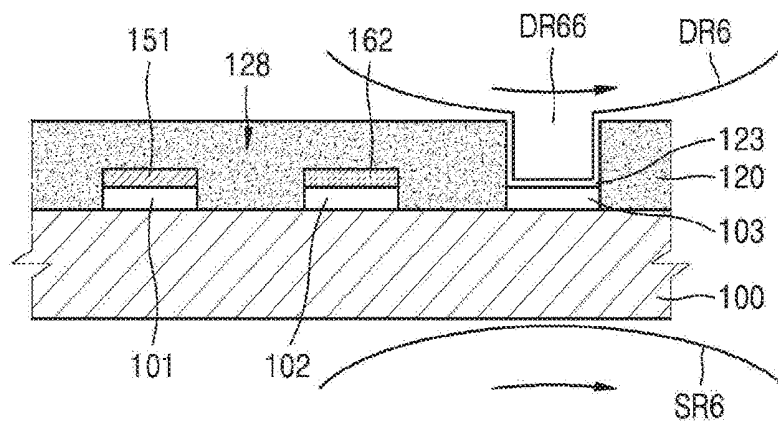


FIG. 12C

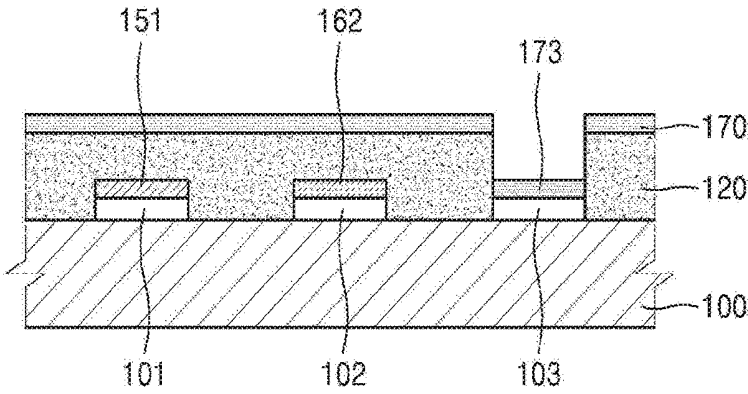
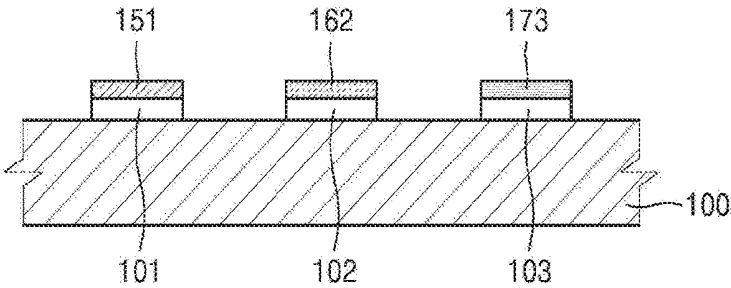


FIG. 12D



METHOD OF MANUFACTURING ORGANIC LIGHT-EMITTING DISPLAY APPARATUS

CROSS-REFERENCE TO RELATED APPLICATION

This application claims priority from and the benefit of Korean Patent Application No. 10-2015-0119825, filed on Aug. 25, 2015, which is hereby incorporated by reference for all purposes as if fully set forth herein.

BACKGROUND

Field

Exemplary embodiments relate to a method of manufacturing an organic light-emitting display apparatus.

Discussion of the Background

Organic light-emitting display apparatuses may be self-luminous display apparatuses having a hole injection electrode, an electron injection electrode, and an organic light-emitting layer between the hole injection electrode and the electron injection electrode. As holes injected by the hole injection electrode and electrons injected by the electron injection electrode are combined and become neutral in the organic light-emitting layer, light is emitted. An organic light-emitting display apparatus has been highlighted as a next generation display apparatus having high quality characteristics, for example, low power consumption, high brightness, and fast response speed.

The above information disclosed in this Background section is only for enhancement of understanding of the background of the inventive concept, and, therefore, it may contain information that does not form the prior art that is already known in this country to a person of ordinary skill in the art.

SUMMARY

Exemplary embodiments provide a method of manufacturing an organic light-emitting display apparatus which may reduce manufacturing costs thereof.

Additional aspects will be set forth in the detailed description which follows, and, in part, will be apparent from the disclosure, or may be learned by practice of the inventive concept.

According to an exemplary embodiment of the present invention, a method of manufacturing an organic light-emitting display apparatus includes forming an anode on a substrate, forming a lift-off layer on the substrate including the anode, the lift-off layer including a fluoropolymer, forming a polymer layer on the lift-off layer, forming a pattern on a first portion of the polymer layer overlapping the anode using a roll-to-roll stamp process, etching a first portion of the lift-off layer corresponding to the pattern using a first solvent including fluorine, the first portion of the lift-off layer being disposed on the anode, forming an organic functional layer including a light-emitting layer on the anode and a second portion of the polymer layer not formed with the pattern, removing the lift-off layer using a second solvent including fluorine, and forming a cathode on the organic functional layer.

According to an exemplary embodiment of the present invention, a method of manufacturing an organic light-emitting display apparatus includes forming an anode on a substrate, forming a lift-off layer on the substrate including the anode, the lift-off layer including a fluoropolymer, forming a pattern on a first portion the lift-off layer over-

lapping the anode using a roll-to-roll stamp process, forming an organic functional layer including a light-emitting layer on the anode and on a second portion of the lift-off layer not formed with the pattern, removing the lift-off layer using a solvent including fluorine, and forming a cathode on the organic functional layer.

According to an exemplary embodiment of the present invention, a method of manufacturing an organic light-emitting display apparatus includes forming a first anode and a second anode spaced apart from each other on a substrate, performing a unit process on each of the first and second anodes, and forming a cathode after performing the unit process for each of the first and second anodes. The unit process includes forming a lift-off layer on the substrate, the lift-off layer including a fluoropolymer, forming a polymer layer on the lift-off layer, forming a pattern on a first portion of the polymer layer overlapping a corresponding anode using a roll-to-roll stamp process, etching a first portion of the lift-off layer corresponding to the pattern using a first solvent including fluorine, forming an organic functional layer including a light-emitting layer on the corresponding anode and on a second portion of the polymer layer not formed with the pattern, and removing the lift-off layer using a second solvent including fluorine. A first organic light emitting layer disposed on the first anode and a second organic light emitting layer disposed on the second anode are configured to emit different colored light.

According to an exemplary embodiment of the present invention, a method of manufacturing an organic light-emitting display apparatus includes forming a first anode and a second anode spaced apart from each other on a substrate, performing a unit process on each of the first and second anodes, and forming a cathode after performing the unit process for each of the first and second anodes. The unit process includes forming a lift-off layer including a fluoropolymer on the substrate, forming a pattern on a first portion of the lift-off layer overlapping a corresponding anode using a roll-to-roll stamp process, forming an organic functional layer including a light-emitting layer on the corresponding anode and a second portion of the lift-off layer not formed with the pattern, and removing the lift-off layer using a solvent including fluorine. A first organic light emitting layer disposed on the first anode and a second organic light emitting layer disposed on the second anode are configured to emit different colored light.

The foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the claimed subject matter.

BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which are included to provide a further understanding of the inventive concept, and are incorporated in and constitute a part of this specification, illustrate exemplary embodiments of the inventive concept, and, together with the description, serve to explain principles of the inventive concept.

FIG. 1 is a flowchart of a manufacturing method of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention.

FIG. 2 is a cross-sectional view schematically illustrating anodes formed on a substrate, according to an exemplary embodiment of the present invention.

FIG. 3A, FIG. 3B, FIG. 3C, FIG. 3D, FIG. 3E, and FIG. 3F are cross-sectional views schematically illustrating a first unit operation of the manufacturing method of FIG. 1.

FIG. 4A, FIG. 4B, FIG. 4C, FIG. 4D, FIG. 4E, and FIG. 4F are cross-sectional views schematically illustrating a second unit operation of the manufacturing method of FIG. 1.

FIG. 5A, FIG. 5B, FIG. 5C, FIG. 5D, FIG. 5E, and FIG. 5F are cross-sectional views schematically illustrating a third unit operation of the manufacturing method of FIG. 1.

FIG. 6 is a schematic cross-sectional view of an organic light-emitting display apparatus manufactured by the manufacturing method of FIG. 1.

FIG. 7 is a schematic cross-sectional view of an organic light-emitting display apparatus manufactured by a manufacturing method according to an exemplary embodiment of the present invention.

FIG. 8 is a schematic cross-sectional view of an organic light-emitting display apparatus manufactured by a manufacturing method according to an exemplary embodiment of the present invention.

FIG. 9 is a flowchart of a manufacturing method of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention.

FIG. 10A, FIG. 10B, FIG. 10C, and FIG. 10D are cross-sectional views schematically illustrating a first unit operation of the manufacturing method of FIG. 9.

FIG. 11A, FIG. 11B, FIG. 11C, and FIG. 11D are cross-sectional views schematically illustrating a second unit operation of the manufacturing method of FIG. 9.

FIG. 12A, FIG. 12B, FIG. 12C, and FIG. 12D are cross-sectional views schematically illustrating a third unit operation of the manufacturing method of FIG. 9.

DETAILED DESCRIPTION OF THE ILLUSTRATED EMBODIMENTS

In the following description, for the purposes of explanation, numerous specific details are set forth in order to provide a thorough understanding of various exemplary embodiments. It is apparent, however, that various exemplary embodiments may be practiced without these specific details or with one or more equivalent arrangements. In other instances, well-known structures and devices are shown in block diagram form in order to avoid unnecessarily obscuring various exemplary embodiments.

In the accompanying figures, the size and relative sizes of layers, films, panels, regions, etc., may be exaggerated for clarity and descriptive purposes. Also, like reference numerals denote like elements.

When an element or layer is referred to as being “on,” “connected to,” or “coupled to” another element or layer, it may be directly on, connected to, or coupled to the other element or layer or intervening elements or layers may be present. When, however, an element or layer is referred to as being “directly on,” “directly connected to,” or “directly coupled to” another element or layer, there are no intervening elements or layers present. For the purposes of this disclosure, “at least one of X, Y, and Z” and “at least one selected from the group consisting of X, Y, and Z” may be construed as X only, Y only, Z only, or any combination of two or more of X, Y, and Z, such as, for instance, XYZ, XYY, YZ, and ZZ. Like numbers refer to like elements throughout. As used herein, the term “and/or” includes any and all combinations of is one or more of the associated listed items.

Although the terms first, second, etc. may be used herein to describe various elements, components, regions, layers, and/or sections, these elements, components, regions, layers, and/or sections should not be limited by these terms. These

terms are used to distinguish one element, component, region, layer, and/or section from another element, component, region, layer, and/or section. Thus, a first element, component, region, layer, and/or section discussed below could be termed a second element, component, region, layer, and/or section without departing from the teachings of the present disclosure.

Spatially relative terms, such as “beneath,” “below,” “lower,” “above,” “upper,” and the like, may be used herein for descriptive purposes, and, thereby, to describe one element or feature’s relationship to another element(s) or feature(s) as illustrated in the drawings. Spatially relative terms are intended to encompass different orientations of an apparatus in use, operation, and/or manufacture in addition to the orientation depicted in the drawings. For example, if the apparatus in the drawings is turned over, elements described as “below” or “beneath” other elements or features would then be oriented “above” the other elements or features. Thus, the exemplary term “below” can encompass both an orientation of above and below. Furthermore, the apparatus may be otherwise oriented (e.g., rotated 90 degrees or at other orientations), and, as such, the spatially relative descriptors used herein interpreted accordingly.

The terminology used herein is for the purpose of describing particular embodiments and is not intended to be limiting. As used herein, the singular forms, “a,” “an,” and “the” are intended to include the plural forms as well, unless the context clearly indicates otherwise. Moreover, the terms “comprises,” “comprising,” “includes,” and/or “including,” when used in this specification, specify the presence of stated features, integers, steps, operations, elements, components, and/or groups thereof, but do not preclude the presence or addition of one or more other features, integers, steps, operations, elements, components, and/or groups thereof.

Various exemplary embodiments are described herein with reference to sectional illustrations that are schematic illustrations of idealized exemplary embodiments and/or intermediate structures. As such, variations from the shapes of the illustrations as a result, for example, of manufacturing techniques and/or tolerances, are to be expected. Thus, exemplary embodiments disclosed herein should not be construed as limited to the particular illustrated shapes of regions, but are to include deviations in shapes that result from, for instance, manufacturing. For example, an implanted region illustrated as a rectangle will, typically, have rounded or curved features and/or a gradient of implant concentration at its edges rather than a binary change from implanted to non-implanted region. Likewise, a buried region formed by implantation may result in some implantation in the region between the buried region and the surface through which the implantation takes place. Thus, the regions illustrated in the drawings are schematic in nature and their shapes are not intended to illustrate the actual shape of a region of a device and are not intended to be limiting.

Unless otherwise defined, all terms (including technical and scientific terms) used herein have the same meaning as commonly understood by one of ordinary skill in the art to which this disclosure is a part. Terms, such as those defined in commonly used dictionaries, should be interpreted as having a meaning that is consistent with their meaning in the context of the relevant art and will not be interpreted in an idealized or overly formal sense, unless expressly so defined herein.

FIG. 1 is a flowchart of a manufacturing method of an organic light-emitting display apparatus according to an exemplary embodiment of the present invention.

Referring to FIG. 1, in the method of manufacturing an organic light-emitting display apparatus 1 according to the present exemplary embodiment, an anode is formed on a substrate, per step S10. In step S20, a lift-off layer including fluoropolymer is formed on the substrate including the anode. In step S30, a polymer layer is formed on the lift-off layer and a pattern is formed on the polymer layer by a roll-to-roll stamp process.

In step S40, a portion of the lift-off layer, on which the pattern is formed, above the anode, is etched using a first solvent including fluorine. In step S50, an organic functional layer including a light-emitting layer is formed above the anode and above the area where the polymer layer remains. In step S60, the lift-off layer is removed by using a second solvent including fluorine. In step S70, a cathode is formed on the organic light-emitting layer.

The manufacturing method according to an exemplary embodiment of the present invention will be described in detail with reference to FIGS. 2 to 6.

FIG. 2 is a cross-sectional view schematically illustrating anodes formed on a substrate according to an exemplary embodiment of the present invention. FIGS. 3A to 3F are cross-sectional views schematically illustrating a first unit operation of the manufacturing method of FIG. 1. FIGS. 4A to 4F are cross-sectional views schematically illustrating a second unit operation of the manufacturing method of FIG. 1. FIGS. 5A to 5F are cross-sectional views schematically illustrating a third unit operation of the manufacturing method of FIG. 1. FIG. 6 is a schematic cross-sectional view of an organic light-emitting display apparatus 1 manufactured by the manufacturing method of FIG. 1.

Referring to FIG. 2, anodes including a first anode 101, a second anode 102, and a third anode 103 are formed on a substrate 100.

The substrate 100 may be formed of a flexible material including glass or plastic. For example, the plastic may be formed of a material having excellent thermal resistance and durability characteristics, such as polyimide, polyethylenenaphthalate, polyethyleneterephthalate, polyarylate, polycarbonate, polyetherimide, or polyethersulfone.

Although not illustrated in FIG. 2, a planar surface may be formed above the substrate 100 and a buffer layer (not shown) may be further formed on the planar surface to prevent intrusion of impurities. The buffer layer may include silicon nitride and/or silicon oxide in a single layer or a multiple layer.

The first, second, and third anodes 101, 102, and 103, as hole injection electrodes, may include a material having relatively large work function. The first to third anodes 101, 102, and 103 may include at least one of indium tin oxide, indium zinc oxide, zinc oxide, indium oxide, indium gallium oxide, and aluminum zinc oxide.

Although not illustrated in FIG. 2, the first, second, and third anodes 101, 102, and 103 may be electrically connected to first, second, and third thin-film transistors (not shown), respectively, located between the substrate 100 and the first to third anodes 101, 102, and 103.

Referring to FIG. 3A, a lift-off layer 120 including fluoropolymer is formed on the substrate 100, on which the first to third anodes 101, 102, and 103 are formed.

The fluoropolymer included in the lift-off layer 120 may be a polymer having a fluorine content of about 10 to 60 wt %. For example, the fluoropolymer included in the lift-off layer 120 may include at least one of polytetrafluoroethyl-

ene, polychlorotrifluoroethylene, polydichlorodifluoroethylene, a copolymer of chlorotrifluoroethylene and dichlorodifluoroethylene, a copolymer of tetrafluoroethylene and perfluoroalkylvinylether, a copolymer of chlorotrifluoroethylene and perfluoroalkylvinylether, a copolymer of tetrafluoroethylene and perfluoroalkylvinylether, and a copolymer of chlorotrifluoroethylene and perfluoroalkylvinylether.

The lift-off layer 120 may be formed on the substrate 100 by, for example, a coating method, a printing method, or a deposition method. When the lift-off layer 120 is formed by a coating method or a printing method, a patterning process may be performed after a curing and polymerization process is performed.

The thickness of the lift-off layer 120 may be equal to or greater than about 0.2 μm and equal to or less than about 5 μm . When the thickness of the lift-off layer 120 is too thick, a time to melt the lift-off layer 120 for patterning increases, which may increase a manufacturing process time. When the thickness of the lift-off layer 120 is too thin, it may be difficult to perform a lift-off process.

Referring to FIG. 3B, a polymer layer 130 is formed on the lift-off layer 120.

The polymer layer 130 may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller DR1 (see FIG. 3C), to form a pattern by a roll-to-roll stamp process, which will be described in more detail with reference to FIG. 3C. The polymer layer 130 may further include UV cured resin or heat cured resin.

A glass transition temperature of the polymer layer 130 may be equal to or greater than 50° C. and equal to or less than 130° C. When the temperature is too low, it may be difficult to generate glass transition on the polymer layer 130. When the temperature is too high, thermal stress may be applied to the lift-off layer 120 or an organic functional layer 151 (see FIG. 3E) including a light-emitting layer.

Referring to FIG. 3C, a first debossed pattern 131 is formed on the polymer layer 130 by a roll-to-roll stamp process. The structure of FIG. 3B is interposed between the drive roller DR1 and a support roller SR1.

While the driver roller DR1 is aligned, such that a first embossed pattern DR11 of the drive roller DR1 is located at a portion of the polymer layer 130 corresponding to the first anode 101, the drive roller DR1 is rotated to press the polymer layer 130. The support roller SR1 is located under the substrate 100 to support the substrate 100, while the drive roller DR1 proceeds over the polymer layer 130.

The drive roller DR1 may include a temperature regulator (not shown). A temperature range provided by the drive roller DR1 is higher than a glass transition temperature of the polymer layer 130. The polymer layer 130 reaching the glass transition temperature may be in a soft state. In this manner, the first debossed pattern 131 is formed in a portion of the polymer layer 130 stamped by the first embossed pattern DR11 of the drive roller DR1.

When the polymer layer 130 includes UV cured resin, the polymer layer 130 may be cured by forming the first debossed pattern 131 on the polymer layer 130 and then directly irradiating a UV light to the first debossed pattern 131. When the polymer layer 130 includes heat cured resin, the polymer layer 130 may be cured by forming the first debossed pattern 131 on the polymer layer 130, and then performing a thermal treatment process on the first debossed pattern 131. An area 136 of the polymer layer 130, where the first embossed pattern DR11 of the drive roller DR1 does not pass, remains un-patterned.

Although FIG. 3C illustrates a structure of forming the first debossed pattern **131** only on the polymer layer **130**, the first debossed pattern **131** may be formed on an upper portion of the lift-off layer **120** by changing the structure of the first embossed pattern **DR11** of the drive roller **DR1** or adjusting a stamping pressure.

Referring to FIG. 3D, the lift-off layer **120** is etched by using the first debossed pattern **131** formed on the polymer layer **130** of FIG. 3C.

Since the lift-off layer **120** includes fluoropolymer, a solvent capable of etching the fluoropolymer may be used as an etchant. A first solvent (not shown) including fluorine may be used as the etchant. The first solvent may include hydrofluoroether. The hydrofluoroether is an electrochemically stable material due to its low interaction with other materials, and is an environmentally stable material due to its low global warming potential and toxicity.

In an etching process, a portion of the lift-off layer **120** corresponding to the first debossed pattern **131**, that is, above the first anode **101**, is etched. More particularly, the portion of the lift-off layer **120** disposed on the first anode **101** is etched using the above-described first solvent including hydrofluoroether.

During the etching of the lift-off layer **120**, the first solvent including fluorine forms a first undercut profile **UC1** in the lift-off layer **120** disposed under an interface of the area **136** (see FIG. 3E), where the polymer layer **130** remains.

The first undercut profile **UC1** may enable forming a delicate deposition pattern of the first organic light-emitting layer **151** in a deposition process, which will be described in more detail with reference to FIG. 3E, and a clear removal of the lift-off layer **120** remaining on the substrate **100** in a lift-off process, which will be described in more detail with reference to FIG. 3F.

Referring to FIG. 3E, a first organic functional layer **150** including a first organic light-emitting layer **151** is formed on the structure of FIG. 3D. The first organic functional layer **150** may further include at least one of a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer. In the present exemplary embodiment, the first organic light-emitting layer **151** is used as an example of the first organic functional layer **150**. Hereinafter, for descriptive convenience, the first organic functional layer and the first organic light-emitting layer may have the same reference numeral.

The first organic light-emitting layer **150** may be formed by a vacuum deposition method. In the deposition process, the lift-off layer **120** and the polymer layer **130** function as masks. In this manner, a portion **151** of the first organic light-emitting layer **150** is disposed on the first anode **101**, and the first organic light-emitting layer **150** is disposed on the area **136**, where the polymer layer **130** remains.

Referring to FIG. 3F, a lift-off process is performed on the structure of FIG. 3E.

Since the lift-off layer **120** includes fluoropolymer, a second solvent including fluorine is used in the lift-off process. Since the lift-off process is performed after the first organic light-emitting layer **150** is formed, a material having a low reactivity to the organic light-emitting layer **150** is used as the second solvent. The second solvent may include hydrofluoroether.

As a lift-off layer **126** formed under the area **136** where the polymer layer **130** remains (see FIG. 3E) is lifted off, the first organic light-emitting layer **150** disposed on the area **136**, where the polymer layer **130** remains, is removed, and,

thus the first organic light-emitting layer **151** formed on the first anode **101** is left as a pattern.

According to the present exemplary embodiment, since the pattern of the first organic light-emitting layer **151** is formed in the lift-off process, rather than being deposited using a metal mask (not shown) having an opening, a misalignment between the substrate **100** and the metal mask may be prevented. Also, since the patterning of the lift-off layer **120** is performed by a roll-to-roll stamp process, rather than a photolithography process, process costs may be reduced.

A second unit process of forming a second organic light-emitting layer **162** (see FIG. 4F) emitting light of a color different from that of the first organic light-emitting layer **151** is performed in an area where the second anode **102** is disposed, after performing the above-described first unit process. The second unit process will be described below with reference to FIGS. 4A to 4F.

Referring to FIG. 4A, the lift-off layer **120** including fluoropolymer is formed on the substrate **100** where the first, second, and third anodes **101**, **102**, and **103** are formed.

The lift-off layer **120** may include a material that is the same as or different from the fluoropolymer used in the first unit process. The lift-off layer **120** may be formed on the substrate **100** by, for example, a coating method, a printing method, or a deposition method.

Referring to FIG. 4B, the polymer layer **130** is formed on the lift-off layer **120**.

The polymer layer **130** may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller **DR2** (see FIG. 4C), to form a pattern by a roll-to-roll stamp process, which will be described in more detail with reference to FIG. 4C. The polymer layer **130** may include a material that is the same as or different from the polymer layer used in the first unit process.

Referring to FIG. 4C, a second debossed pattern **132** is formed on the polymer layer **130** by a roll-to-roll stamp process. The structure of FIG. 4B is interposed between the drive roller **DR2** and a support roller **SR2**.

While the driver roller **DR2** is aligned, such that a second embossed pattern **DR22** of the drive roller **DR2** is located at a portion of the polymer layer **130** corresponding to the second anode **102**, the drive roller **DR2** is rotated to press the polymer layer **130**. The support roller **SR2** is located under the substrate **100** to support the substrate **100**, while the drive roller **DR2** proceeds over the polymer layer **130**.

The polymer layer **130** reaching the glass transition temperature by heat transferred by the drive roller **DR2** may be in a soft state. In this manner, the second debossed pattern **132** is formed in a portion of the polymer layer **130** stamped by the second embossed pattern **DR22** of the drive roller **DR2**. An area **137** of the polymer layer **130**, where the second embossed pattern **DR22** of the drive roller **DR2** does not pass, remains un-patterned.

Although FIG. 4C illustrates a structure of forming the second debossed pattern **132** only on the polymer layer **130**, the second debossed pattern **132** may be formed on an upper portion of the lift-off layer **120** by changing the structure of the second embossed pattern **DR22** of the drive roller **DR2** or adjusting a stamping pressure.

Referring to FIG. 4D, the lift-off layer **120** is etched by using the second debossed pattern **132** formed on the polymer layer **130** of FIG. 4C. Since the lift-off layer **120** includes fluoropolymer, a solvent capable of etching fluoropolymer may be used as an etchant. A first solvent (not shown) including fluorine may be used as the etchant. The

first solvent may include hydrofluoroether, as in the above-described first unit process. The content of fluorine of the first solvent may be different from that utilized in the first unit process.

In the etching process, a portion of the lift-off layer **120** corresponding to the second debossed pattern **132**, that is, above the second anode **102**, is etched. More particularly, the portion of the lift-off layer **120** disposed on the second anode **102** is etched using the above-described first solvent including hydrofluoroether.

During the etching of the lift-off layer **120**, the first solvent including fluorine forms a second undercut profile UC2 in the lift-off layer **120** disposed under an interface of the area **137** (see FIG. 4E), where the polymer layer **130** remains.

Referring to FIG. 4E, a second organic functional layer **160** including a second organic light-emitting layer is formed on the structure of FIG. 4D. The second organic functional layer **160** may include at least one functional layer of a hole injection layer, a hole transport layer, an electron injection layer, and an electron injection layer. In the present exemplary embodiment, the second organic light-emitting layer is used as an example of the second organic functional layer **160**. Hereinafter, for convenience of description, the second organic functional layer and the second organic light-emitting layer may have the same reference numeral.

The second organic light-emitting layer **160** may be formed by a vacuum deposition method. In the deposition process, the lift-off layer **120** and the polymer layer **130** function as masks. In this manner, a portion **162** of the second organic light-emitting layer **160** is disposed on the second anode **102**, and the second organic light-emitting layer **160** is formed on the area **137**, where the polymer layer **130** remains.

Referring to FIG. 4F, a lift-off process is performed on the structure of FIG. 4E.

Since the lift-off layer **120** includes fluoropolymer, a second solvent including fluorine is used in the lift-off process. Since the lift-off process is performed after the second organic light-emitting layer **160** is formed, a material having a low reactivity to the second organic light-emitting layer **160** may be used as the second solvent. The second solvent may include hydrofluoroether, like the first solvent.

As a lift-off layer **127** formed under the area **137** (see FIG. 4E), where the polymer layer **130** remains, is lifted off, the second organic light-emitting layer **160** disposed on the area **137**, where the polymer layer **130** remains, is removed, and the second organic light-emitting layer **162** formed on the second anode **102** is left as a pattern.

A third unit process of forming a third organic light-emitting layer **173** (see FIG. 5F) emitting light of a color different from that of the first and second organic light-emitting layers **151** and **162** is performed in an area where the third anode **103** is located, after performing the above-described first and second unit processes. The third unit process will be described below with reference to FIGS. 5A to 5F.

Referring to FIG. 5A, the lift-off layer **120** including fluoropolymer is formed on the substrate **100** where the first, second, and third anodes **101**, **102**, and **103** are formed.

The lift-off layer **120** may include a material that is the same as or different from the fluoropolymer used in the first and second unit processes. The lift-off layer **120** may be formed on the substrate **100** by, for example, a coating method, a printing method, or a deposition method.

Referring to FIG. 5B, the polymer layer **130** is formed on the lift-off layer **120**.

The polymer layer **130** may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller DR3 (see FIG. 5C) to form a pattern, by a roll-to-roll stamp process. The polymer layer **130** may include a material that is the same as or different from the polymer layer used in the first and second unit processes.

Referring to FIG. 5C, a third debossed pattern **133** is formed on the polymer layer **130** by a roll-to-roll stamp process. The structure of FIG. 5B is interposed between the drive roller DR3 and a support roller SR3.

While the driver roller DR3 is aligned, such that a third embossed pattern DR33 of the drive roller DR3 is located at a portion of the polymer layer **130** corresponding to the third anode **103**, the drive roller DR3 is rotated to press the polymer layer **130**. The support roller SR3 is located under the substrate **100** to support the substrate **100** while the drive roller DR3 proceeds over the polymer layer **130**.

The polymer layer **130** reaching the glass transition temperature by heat transferred by the drive roller DR3 may be in a soft state. In this manner, the third debossed pattern **133** is formed in a portion of the polymer layer **130** stamped by the third embossed pattern DR33 of the drive roller DR3. An area **138** of the polymer layer **130**, where the third embossed pattern DR33 of the drive roller DR3 does not pass, remains un-patterned.

Although FIG. 5C illustrates a structure of forming the third debossed pattern **133** only on the polymer layer **130**, the third debossed pattern **133** may be formed on an upper portion of the lift-off layer **120** by changing the structure of the third embossed pattern DR33 of the drive roller DR3 or adjusting a stamping pressure.

Referring to FIG. 5D, the lift-off layer **120** is etched using the third debossed pattern **133** formed on the polymer layer **130** of FIG. 5C.

Since the lift-off layer **120** includes fluoropolymer, a solvent capable of etching fluoropolymer may be used as an etchant. A first solvent (not shown) including fluorine may be used as the etchant. The first solvent may include hydrofluoroether, as in the above-described first unit process. The content of fluorine in the first solvent may be different from that utilized in the first unit process.

In the etching process, a portion of the lift-off layer **120** corresponding to the third debossed pattern **133**, that is, above the third anode **103**, is etched. More particularly, the portion of the lift-off layer **120** disposed on the third anode **103** is etched using the above-described first solvent including hydrofluoroether.

During the etching of the lift-off layer **120**, the first solvent including fluorine forms a third undercut profile UC3 in the lift-off layer **120** disposed under an interface of the area **138** (see FIG. 5E) where the polymer layer **130** remains.

Referring to FIG. 5E, the third organic functional layer **170** including a third organic light-emitting layer is disposed on the structure of FIG. 5D. The third organic functional layer **170** may further include at least one functional layer of a hole injection layer, a hole transport layer, an electron injection layer, and an electron injection layer. In the present exemplary embodiment, the third organic light-emitting layer is used as an example of the third organic functional layer **170**. Hereinafter for descriptive convenience, the third organic functional layer and the third organic light-emitting layer may have the same reference numeral.

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The third organic light-emitting layer **170** may be formed by a vacuum deposition method. In the deposition process, the lift-off layer **120** and the polymer layer **130** function as masks. In this manner, a portion **173** of the third organic light-emitting layer **170** is disposed on the third anode **103**, and the third organic light-emitting layer **170** is formed on the area **138**, where the polymer layer **130** remains.

Referring to FIG. 5F, a lift-off process is performed on the structure of FIG. 5E.

Since the lift-off layer **120** includes fluoropolymer, a second solvent including fluorine is used in the lift-off process. Since the lift-off process is performed after the third organic light-emitting layer **170** is formed, a material having a low reactivity to the third organic light-emitting layer **170** may be used as the second solvent. The second solvent may include hydrofluoroether, like the first solvent.

As a lift-off layer **128** formed under the area **138** (see FIG. 5E), where the polymer layer **130** remains, is lifted off, the third organic light-emitting layer **170** disposed on the area **137**, where the polymer layer **130** remains, is removed, and, thus the portion **173** of the third organic light-emitting layer **170** disposed on the third anode **103** is left as a pattern.

Referring to FIG. 6, after the first, second, and third organic functional layers **151**, **162**, and **173** are formed through the first, second, and third unit processes, a cathode **180** is disposed thereon as a common layer.

Although FIG. 6 illustrates that the cathodes **180** formed on the first to third anodes **101**, **102**, and **103** are separately formed, the present disclosure is not limited thereto and the cathodes **180** may be integrally formed.

The first, second, and third organic light-emitting layers **151**, **162**, and **173** may emit lights of different colors. The light emitted by the first to third organic light-emitting layers **151**, **162**, and **173** may appear as a white light when mixed together. For example, the first to third organic light-emitting layers **151**, **162**, and **173** may emit light of red, green, and blue, respectively. For example, the first to third organic light-emitting layers **151**, **162**, and **173** may define subpixels forming a unit pixel of the organic light-emitting display apparatus **1**. The organic light-emitting display apparatus **1** of FIG. 6 may indicate one unit pixel.

The organic light-emitting display apparatus according to the present exemplary embodiment illustrated with reference to FIG. 6 may be applied to an organic light-emitting display apparatus having multiple unit pixels.

For example, referring to FIG. 3C, in the first unit process, the first debossed patterns **131** may be formed on the polymer layer **130** by using the drive roller DR1 having the first embossed patterns DR11, and the first organic light-emitting layers **151** for emitting a first color may be simultaneously formed on the first anodes **101** using the first debossed patterns **131** as etching masks.

In the second unit process, referring to FIG. 4C, the second debossed patterns **132** may be formed on the polymer layer **130** by using the drive roller DR2 having the second embossed patterns DR22, and the second organic light-emitting layers **162** for emitting a second color may be simultaneously formed on the second anodes **102** using the second debossed patterns **132** as etching masks.

In the third unit process, referring to FIG. 5C, the third debossed patterns **133** may be formed on the polymer layer **130** by using the drive roller DR3 having the third embossed patterns DR33, and the third organic light-emitting layers **173** for emitting a third color may be simultaneously formed on the third anodes **103** using the third debossed patterns **133** as etching masks. In this manner, the organic light-emitting

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display apparatus **1** may embody a full color through the above-described first to third unit processes.

FIG. 7 is a schematic cross-sectional view of an organic light-emitting display apparatus **2** manufactured by a manufacturing method according to an exemplary embodiment of the present invention.

A manufacturing method of the organic light-emitting display apparatus **2** of FIG. 7 may be similar to the above-described manufacturing method of the organic light-emitting display apparatus **1** of FIG. 6. Hereinafter, differences from the above-described manufacturing method of the organic light-emitting display apparatus **1** of FIG. 6 will be mainly described.

Referring to FIG. 7, first, second, and third anodes **101**, **102**, and **103** are formed on the substrate **100**. A pixel-defining layer **110** is disposed to surround the edges of the first to third anodes **101**, **102**, and **103**. The pixel-defining layer **110** defines a light-emitting area and prevents short-circuit between the first to third anodes **101**, **102**, and **103** and a cathode **180**.

In the present exemplary embodiment, the first, second, and third unit processes are performed after forming the first to third anodes **101**, **102**, and **103** and the pixel-defining layer **110**. Through the first to third unit processes, the first, second, and third organic light-emitting layers **151**, **162**, and **173** are respectively formed on the first, second, and third anodes **101**, **102**, and **103**, and the cathode **180** is formed as a common layer.

FIG. 8 is a schematic cross-sectional view of an organic light-emitting display apparatus **3** manufactured by a manufacturing method according to an exemplary embodiment of the present invention.

A manufacturing method of the organic light-emitting display apparatus **3** of FIG. 8 may be similar to the above-described manufacturing method of the organic light-emitting display apparatus **2** of FIG. 7. Hereinafter, differences from the above-described manufacturing method of the organic light-emitting display apparatus **2** of FIG. 7 will be mainly described.

Referring to FIG. 8, anodes including first, second, and third anodes **101**, **102**, and **103** are formed on the substrate **100**. The pixel-defining layer **110** is disposed to surround the edges of the first to third anodes **101**, **102**, and **103**. The pixel-defining layer **110** defines a light-emitting area and prevents short-circuit between the first to third anodes **101**, **102**, and **103** and the cathode **180**. In the present exemplary embodiment, the first, second, and third unit processes are performed after forming the first to third anodes **101**, **102**, and **103** and the pixel-defining layer **110**.

In the first unit process, referring back to FIG. 3C, the lift-off layer **120** disposed on the first anode **101** is etched by a roll-to-roll stamping process and an etching process. Next, the first organic light-emitting layer **151** is formed on the first anode **101** by a deposition process. When the first organic light-emitting layer **151** is formed, a first auxiliary cathode **181** is continuously deposited on the first organic light-emitting layer **151** and a lift-off process is performed.

During the lift-off process, a second solvent (not shown) including fluorine is used. The second solvent including fluorine may damage the first organic light-emitting layer **151**. As such, the first auxiliary cathode **181** functions as a barrier with respect to the first organic light-emitting layer **151** during the lift-off process.

After the first unit process, the second unit process is performed. Referring back to FIG. 4C, the lift-off layer **120** disposed on the second anode **102** is etched by a roll-to-roll stamping process and an etching process. Next, the second

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organic light-emitting layer **162** is formed on the second anode **102** by a deposition process. When the second organic light-emitting layer **162** is formed, a second auxiliary cathode **182** is continuously deposited on the second organic light-emitting layer **162**, and a lift-off process is performed.

During the lift-off process, a second solvent (not shown) including fluorine is used. The second solvent including fluorine may damage the second organic light-emitting layer **162**. As such, the second auxiliary cathode **182** functions as a barrier with respect to the second organic light-emitting layer **162** during the lift-off process.

After the second unit process, the third unit process is performed. Referring back to FIG. 5C, the lift-off layer **120** disposed on the third anode **103** is etched by a roll-to-roll stamping process and an etching process. Next, the third organic light-emitting layer **173** is formed on the third anode **103** by a deposition process. When the third organic light-emitting layer **173** is formed, a third auxiliary cathode **183** is continuously deposited on the third organic light-emitting layer **173**, and a lift-off process is performed.

During the lift-off process, a second solvent (not shown) including fluorine is used. The second solvent including fluorine may damage the third organic light-emitting layer **173**. As such, the third auxiliary cathode **183** functions as a barrier with respect to the third organic light-emitting layer **173** during the lift-off process. After the first to third unit processes are performed, the cathode **180** is formed as a common layer.

According to the manufacturing method of FIG. 8, since the first, second, and third auxiliary cathodes **181**, **182**, and **183** are continuously deposited on the first, second, and third organic light-emitting layers **151**, **162**, and **173**, respectively, during the deposition of the first to third organic light-emitting layers **151**, **162**, and **173** in the respective unit processes, the first to third organic light-emitting layers **151**, **162**, and **173** may be prevented from being damaged in the subsequent lift-off process. In addition, since the first to third auxiliary cathodes **181**, **182**, and **183** electrically contact the cathode **180**, which is commonly formed on pixels after the first to third unit processes, voltage drop of the cathode **180** may be prevented.

FIG. 9 is a flowchart of a manufacturing method according to an exemplary embodiment of the present invention.

Referring to FIG. 9, in the method of manufacturing an organic light-emitting display apparatus **1** according to the present exemplary embodiment, an anode is formed on a substrate, per step S11. In step S21, the lift-off layer including fluoropolymer is formed on the substrate including the anode, and a pattern is formed on the lift-off layer by a roll-to-roll stamp process.

In step S31, an organic functional layer including a light-emitting layer is formed above the anode and above an area where the polymer layer remains. In step S41, the lift-off layer is removed using a solvent including. In step S51, a cathode is formed on the organic light-emitting layer.

The manufacturing method according to an exemplary embodiment of the present invention is described in detail with reference to FIGS. 10A to 12D.

FIGS. 10A to 10D are cross-sectional views schematically illustrating a first unit operation of the manufacturing method of FIG. 9. FIGS. 11A to 11D are cross-sectional views schematically illustrating a second unit operation of the manufacturing method of FIG. 9. FIGS. 12A to 12D are cross-sectional views schematically illustrating a third unit operation of the manufacturing method of FIG. 9.

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Referring to FIG. 10A, a lift-off layer **120** including fluoropolymer is formed on a substrate **100**, on which the first to third anodes **101**, **102**, and **103** are formed.

Referring to FIG. 10B, a first debossed pattern **121** is formed on the lift-off layer **120** by a roll-to-roll stamp process. In the present exemplary embodiment, the first debossed pattern **121** is formed directly on the lift-off layer **120** without forming the polymer layer **130** of FIG. 3B.

The lift-off layer **120** may include fluoropolymer having a fluorine content of about 10 to 60 wt %. The lift-off layer **120** may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller DR4. The structure of FIG. 10A is interposed between the drive roller DR4 and a support roller SR4.

A glass transition temperature of the lift-off layer **120** may be equal to or greater than 50° C. and equal to or less than 130° C. When the temperature is too low, it may be difficult to generate glass transition on the lift-off layer **120**. When the temperature is too high, thermal stress may be applied to an organic functional layer **151** (see FIG. 10C) including a light-emitting layer.

While the driver roller DR4 is aligned, such that a first embossed pattern DR44 of the drive roller DR4 is located at a portion of the lift-off layer **120** corresponding to the first anode **101**, the drive roller DR4 is rotated to press the lift-off layer **120**. The support roller SR4 is located under the substrate **100** to support the substrate **100** while the drive roller DR4 proceeds over the lift-off layer **120**.

A portion of the lift-off layer **120** reaching the glass transition temperature, due to heat transferred by the drive roller DR4, may be in a soft state. The first debossed pattern **121** is formed in a portion of the lift-off layer **120** stamped by the first embossed pattern DR44 of the drive roller DR4. An area **126** of the lift-off layer **120**, where the first embossed pattern DR44 of the drive roller DR4 does not pass, remains un-patterned.

Referring to FIG. 10C, a first organic functional layer **150** including the first organic light-emitting layer is formed on the structure of FIG. 10B. The first organic functional layer **150** may further include at least one of a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer. In the present exemplary embodiment, the first organic light-emitting layer is used as an example of the first organic functional layer **150**. Hereinafter, the first organic functional layer and the first organic light-emitting layer may have the same reference numeral.

The first organic light-emitting layer **150** may be formed by a vacuum deposition method. In the deposition process, the lift-off layer **120** functions as a mask. In this manner, a portion **151** of the first organic light-emitting layer **150** is disposed on the first anode **101**, and the first organic light-emitting layer **150** is formed in the area **126** where the lift-off layer **120** remains.

Referring to FIG. 10D, a lift-off process is performed on the structure of FIG. 10C.

Since the lift-off layer **120** includes fluoropolymer, a second solvent including fluorine is used in the lift-off process. Since the lift-off process is performed after the first organic light-emitting layer **150** is formed, a material having a low reactivity to the organic light-emitting layer **150** is used as the second solvent. The second solvent may include hydrofluoroether, like the first solvent.

As the lift-off layer **120** disposed in an area **126** is lifted off, the first organic light-emitting layer **150** disposed on the area **126**, where the lift-off layer **120** remains, is removed,

and, thus the first organic light-emitting layer **151** formed on the first anode **101** is left as a pattern.

According to the present exemplary embodiment, since the lift-off layer **120** is used as an etching mask without separately forming the polymer layer **130**, a manufacturing process may be simplified, and, thus process costs may be reduced.

A second unit process of forming a second organic light-emitting layer **162** (see FIG. **11D**) emitting light of a color different from that of the first organic light-emitting layer **151** is performed in an area where the second anode **102** is disposed, after performing the above-described first unit process. The second unit process is described below with reference to FIGS. **11A** to **11D**.

Referring to FIG. **11A**, the lift-off layer **120** including fluoropolymer is formed on the substrate **100**, on which the first to third anodes **101**, **102**, and **103** are formed.

Referring to FIG. **11B**, a second debossed pattern **122** is formed on the lift-off layer **120** by a roll-to-roll stamp process. In the present exemplary embodiment, the second debossed pattern **122** is formed directly on the lift-off layer **120** without forming the polymer layer **130** of FIG. **4B**.

The lift-off layer **120** may include fluoropolymer having a fluorine content of about 10 to 60 wt %. The lift-off layer **120** may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller **DR5**. The structure of FIG. **11A** is interposed between the drive roller **DR5** and a support roller **SR5**.

While the driver roller **DR5** is aligned, such that a second embossed pattern **DR55** of the drive roller **DR5** is located at a portion of the lift-off layer **120** corresponding to the second anode **102**, the drive roller **DR5** is rotated to press the lift-off layer **120**. The support roller **SR5** is located under the substrate **100** to support the substrate **100** while the drive roller **DR5** proceeds over the lift-off layer **120**.

A portion of the lift-off layer **120** reaching the glass transition temperature, due to heat transferred by the drive roller **DR5**, may be in a soft state. The second debossed pattern **122** is formed in a portion of the lift-off layer **120** stamped by the second embossed pattern **DR55** of the drive roller **DR5**. An area **127** of the lift-off layer **120**, where the second embossed pattern **DR55** of the drive roller **DR5** does not pass, remains un-patterned.

Referring to FIG. **11C**, the second organic functional layer **160** including the second organic light-emitting layer is formed on the structure of FIG. **11B**. In the present exemplary embodiment, the second organic light-emitting layer is used as an example of the second organic functional layer **160**. Hereinafter, for descriptive convenience, the second organic functional layer and the second organic light-emitting layer may have the same reference numeral.

The portion **162** of the second organic light-emitting layer **160** is disposed on the second anode **102**, and the second organic light-emitting layer **160** is formed in the area **127** where the lift-off layer **120** remains.

Referring to FIG. **11D**, a lift-off process is performed on the structure of FIG. **11C**.

As the lift-off layer **120** disposed in an area **127** is lifted off, the second organic light-emitting layer **160** disposed on the area **127**, where the lift-off layer **120** remains, is removed, and, thus the second organic light-emitting layer **162** formed on the second anode **102** is left as a pattern.

A third unit process of forming a third organic light-emitting layer **173** (see FIG. **12D**) emitting light of a color different from that of the second organic light-emitting layer **162** is performed in an area where the third anode **103** is

disposed, after performing the above-described second unit process. The third unit process is described below with reference to FIGS. **12A** to **12D**.

Referring to FIG. **12A**, the lift-off layer **120** including fluoropolymer is formed on the substrate **100**, on which the first to third anodes **101**, **102**, and **103** are formed.

Referring to FIG. **12B**, a third debossed pattern **123** is formed on the lift-off layer **120** by a roll-to-roll stamp process. In the present exemplary embodiment, the third debossed pattern **123** is formed directly on the lift-off layer **120** without forming the polymer layer **130** of FIG. **5B**.

The lift-off layer **120** may include fluoropolymer having a fluorine content of about 10 to 60 wt %. The lift-off layer **120** may be formed by various polymer materials, which may generate glass transition within a temperature range provided by a drive roller **DR6**. The structure of FIG. **12A** is interposed between the drive roller **DR6** and a support roller **SR6**.

While the driver roller **DR6** is aligned, such that a third embossed pattern **DR66** of the drive roller **DR6** is located at a portion of the lift-off layer **120** corresponding to the third anode **103**, the drive roller **DR6** is rotated to press the lift-off layer **120**. The support roller **SR6** is located under the substrate **100** to support the substrate **100** while the drive roller **DR6** proceeds over the lift-off layer **120**.

A portion of the lift-off layer **120** reaching the glass transition temperature, due to heat transferred by the drive roller **DR6**, may be in a soft state. The third debossed pattern **123** is formed in a portion of the lift-off layer **120** stamped by the third embossed pattern **DR66** of the drive roller **DR6**. An area **128** of the lift-off layer **120**, where the third embossed pattern **DR66** of the drive roller **DR6** does not pass, remains un-patterned.

Referring to FIG. **12C**, the third organic functional layer **170** including the third organic light-emitting layer is formed on the structure of FIG. **12B**. In the present exemplary embodiment, the third organic light-emitting layer is used as an example of the third organic functional layer **170**. Hereinafter, for descriptive convenience, the third organic functional layer and the third organic light-emitting layer may have the same reference numeral.

The portion **173** of the third organic light-emitting layer **170** is disposed on the third anode **103**, and the third organic light-emitting layer **170** is formed in the area **128** where the lift-off layer **120** remains.

Referring to FIG. **12D**, a lift-off process is performed on the structure of FIG. **12C**.

As the lift-off layer **120** disposed in an area **128** is lifted off, the third organic light-emitting layer **170** disposed on the area **128**, where the lift-off layer **120** remains, is removed, and, thus the third organic light-emitting layer **173** formed on the third anode **103** is left as a pattern.

Although it is not illustrated in the drawings, the above-described organic light-emitting apparatuses **1**, **2**, and **3** may further include an encapsulation member. The encapsulation member may include a glass substrate, a metal foil, or a thin film encapsulation layer mixed with an inorganic layer and an organic layer.

As described above, a method of manufacturing an organic light-emitting display apparatus according to the exemplary embodiments of the present invention may reduce manufacturing costs.

Although certain exemplary embodiments and implementations have been described herein, other embodiments and modifications will be apparent from this description. Accordingly, the inventive concept is not limited to such

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exemplary embodiments, but rather to the broader scope of the presented claims and various obvious modifications and equivalent arrangements.

What is claimed is:

1. A method of manufacturing an organic light-emitting display apparatus, the method comprising:
 - forming an anode on a substrate;
 - forming a lift-off layer on the substrate comprising the anode, the lift-off layer comprising a fluoropolymer;
 - forming a polymer layer on the lift-off layer;
 - forming a pattern on a first portion of the polymer layer overlapping the anode using a roll-to-roll stamp process;
 - etching a first portion of the lift-off layer corresponding to the pattern using a first solvent comprising fluorine, the first portion of the lift-off layer being disposed on the anode;
 - forming an organic functional layer comprising a light-emitting layer on the anode and a second portion of the polymer layer not formed with the pattern;
 - removing the lift-off layer using a second solvent comprising fluorine; and
 - forming a cathode on the organic functional layer.
2. The method of claim 1, wherein the organic functional layer comprises at least one of a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer.
3. The method of claim 1, wherein the organic functional layer is formed by a deposition process.
4. The method of claim 1, wherein a fluorine content of the fluoropolymer is in a range of about 10 wt % to 60 wt %.
5. The method of claim 4, wherein the fluoropolymer comprises at least one of polytetrafluoroethylene, polychlorotrifluoroethylene, polydichlorodifluoroethylene, a copolymer of chlorotrifluoroethylene and dichlorodifluoroethylene, a copolymer of tetrafluoroethylene and perfluoroalkylvinylether, a copolymer of chlorotrifluoroethylene and perfluoroalkylvinylether, a copolymer of tetrafluoroethylene and perfluoroalkylvinylether, and a copolymer of chlorotrifluoroethylene and perfluoroalkylvinylether.
6. The method of claim 1, wherein the first solvent comprises hydrofluoroether.
7. The method of claim 1, wherein the second solvent comprises hydrofluoroether.
8. The method of claim 1, wherein a glass transition temperature of the polymer layer is in a range of 50° C. to 130° C.
9. The method of claim 1, wherein etching the first portion of the lift-off layer comprises forming an undercut profile in

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a second portion of the lift-off layer corresponding to the second portion of the polymer layer.

10. The method of claim 1, further comprising:
 - forming a pixel-defining layer surrounding an edge of the anode.
11. The method of claim 1, further comprising:
 - forming an auxiliary cathode on the organic functional layer, before forming the cathode.
12. A method of manufacturing an organic light-emitting display apparatus, the method comprising:
 - forming a first anode and a second anode spaced apart from each other on a substrate;
 - performing a unit process on each of the first and second anodes, the unit process comprising:
 - forming a lift-off layer on the substrate, the lift-off layer comprising a fluoropolymer;
 - forming a polymer layer on the lift-off layer;
 - forming a pattern on a first portion of the polymer layer overlapping a corresponding anode using a roll-to-roll stamp process;
 - etching a first portion of the lift-off layer corresponding to the pattern using a first solvent comprising fluorine;
 - forming an organic functional layer comprising a light-emitting layer on the corresponding anode and on a second portion of the polymer layer not formed with the pattern; and
 - removing the lift-off layer using a second solvent comprising fluorine; and
 - forming a cathode after performing the unit process for each of the first and second anodes,
 wherein a first organic light emitting layer disposed on the first anode and a second organic light emitting layer disposed on the second anode are configured to emit different colored light.
13. The method of claim 12, wherein the first organic light emitting layer and the second organic light emitting layer are configured to emit mixed light having a white color.
14. The method of claim 12, wherein the unit process further comprises forming organic light emitting layers configured to emit light having the same color.
15. The method of claim 12, wherein the cathode is integrally formed on the first and second organic light emitting layers as a common electrode.
16. The method of claim 12, wherein the unit process further comprises forming an auxiliary cathode on the organic functional layer, before forming the cathode.

* * * * *

专利名称(译)	制造有机发光显示装置的方法		
公开(公告)号	US9818942	公开(公告)日	2017-11-14
申请号	US15/187248	申请日	2016-06-20
[标]申请(专利权)人(译)	三星显示有限公司		
申请(专利权)人(译)	三星DISPLAY CO. , LTD.		
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IPC分类号	H01L51/00 H01L51/56 H01L51/50 H01L51/52 H01L27/32		
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外部链接	Espacenet USPTO		

摘要(译)

制造有机发光显示装置的方法包括在基板上形成阳极，在包括阳极的基板上形成剥离层，剥离层包括含氟聚合物，在剥离时形成聚合物层层，使用卷对卷印模工艺在聚合物层的第一部分上形成与阳极重叠的图案，使用包含氟的第一溶剂蚀刻对应于图案的剥离层的第一部分，第一部分剥离层设置在阳极上，形成包括阳极上的发光层和未形成图案的聚合物层的第二部分的有机功能层，使用第二溶剂去除剥离层包括氟，并在有机功能层上形成阴极。

